

# **NPN General Purpose Amplifier**

This device is designed as a general purpose amplifier and switch. The useful dynamic range extends to 100 mA as a switch and to 100 MHz as an amplifier.

### Absolute Maximum Ratings\* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V <sub>CEO</sub>	Collector-Emitter Voltage	25	V	
V <sub>CBO</sub>	Collector-Base Voltage	30	V	
V <sub>EBO</sub>	Emitter-Base Voltage	5.0	V	
Ic	Collector Current - Continuous	200	mA	
T <sub>J</sub> , T <sub>stg</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C	

\*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

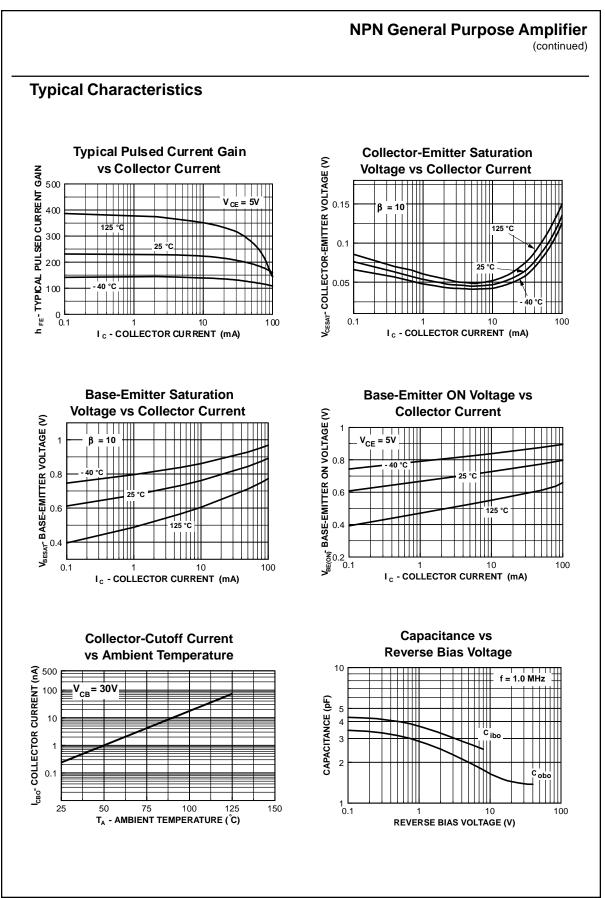
## Thermal Characteristics TA = 25°C unless otherwise noted

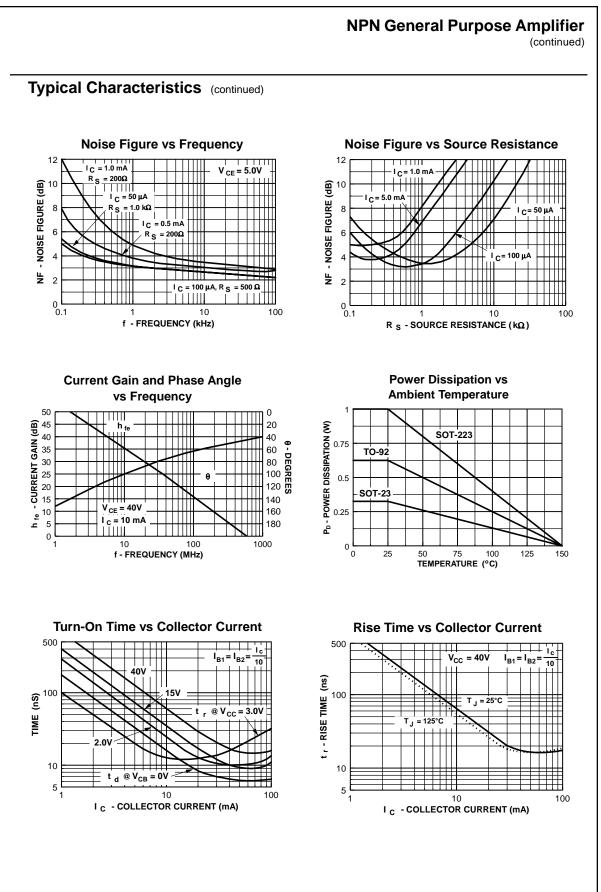
Symbol	Characteristic	Мах		Units
		2N4124	*MMBT4124	
P <sub>D</sub>	Total Device Dissipation	625	350	mW
	Derate above 25°C	5.0	2.8	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3		°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient	200	357	°C/W

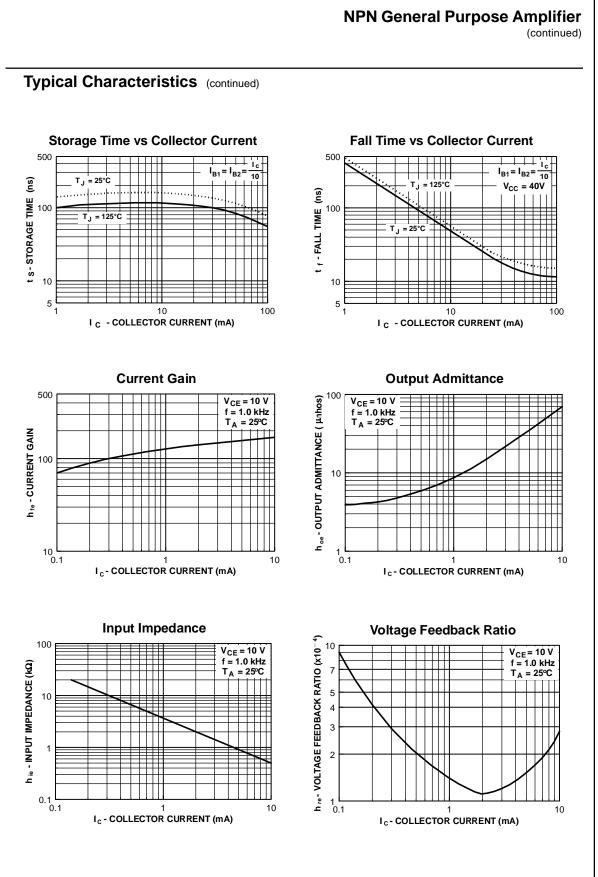
\*Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

# NPN General Purpose Amplifier (continued)

Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHAP	RACTERISTICS				
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	$I_{\rm C} = 1.0 \text{ mA}, I_{\rm B} = 0$	25		V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	$I_{\rm C} = 10 \ \mu {\rm A}, \ I_{\rm E} = 0$	30		V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_{\rm C} = 10 \ \mu {\rm A}, \ I_{\rm C} = 0$	5.0		V
I <sub>CBO</sub>	Collector Cutoff Current	$V_{CB} = 20 \text{ V}, \text{ I}_{E} = 0$		50	nA
I <sub>EBO</sub>	Emitter Cutoff Current	$V_{EB} = 3.0 \text{ V}, \text{ I}_{C} = 0$		50	nA
	ACTERISTICS*				
	DC Current Gain	I <sub>C</sub> = 2.0 mA, V <sub>CE</sub> = 1.0 V	120	360	
··rE		$I_{\rm C} = 2.0$ mA, $V_{\rm CE} = 1.0$ V $I_{\rm C} = 50$ mA, $V_{\rm CE} = 1.0$ V	60	500	
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	$I_{\rm C} = 50 \text{ mA}, I_{\rm B} = 5.0 \text{ mA}$		0.3	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	$I_{\rm C} = 50$ mA, $I_{\rm B} = 5.0$ mA		0.95	V
SMALL SI	GNAL CHARACTERISTICS Current Gain - Bandwidth Product	$I_{C} = 10 \text{ mA}, V_{CE} = 20 \text{ V},$ f = 100 MHz	300		MHz
C <sub>obo</sub>	Output Capacitance	$V_{CB} = 5.0 \text{ V}, I_E = 0,$ f = 100 kHz		4.0	pF
C <sub>ibo</sub>	Input Capacitance	$V_{BE} = 0.5 \text{ V}, I_C = 0,$ f = 1.0 kHz	$_{BE} = 0.5 \text{ V}, \text{ I}_{C} = 0,$		pF
C <sub>cb</sub>	Collector-Base Capcitance	$V_{CB} = 5.0 \text{ V}, I_E = 0,$ f = 100 kHz		4.0	pF
h <sub>fe</sub> NF	Small-Signal Current Gain	$V_{CE} = 10 \text{ V}, I_C = 2.0 \text{ mA},$ f = 1.0 kHz	120	480	dD
INF	Noise Figure	$I_{C}$ = 100 μA, V <sub>CE</sub> = 5.0 V, R <sub>S</sub> =1.0kΩ, f=10 Hz to 15.7 kHz		5.0	dB

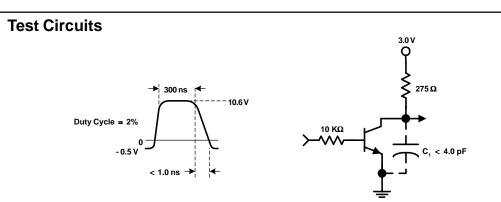




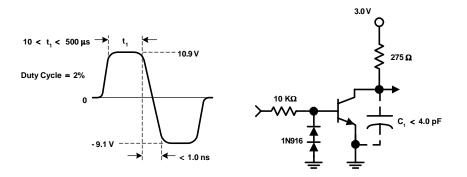


**NPN General Purpose Amplifier** (continued)





#### FIGURE 1: Delay and Rise Time Equivalent Test Circuit







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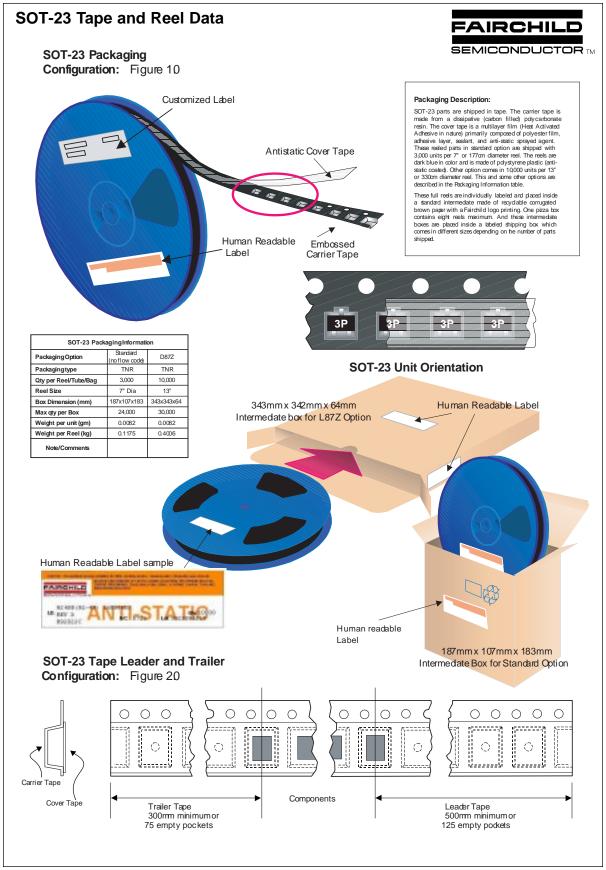
March 2001, Rev. B1





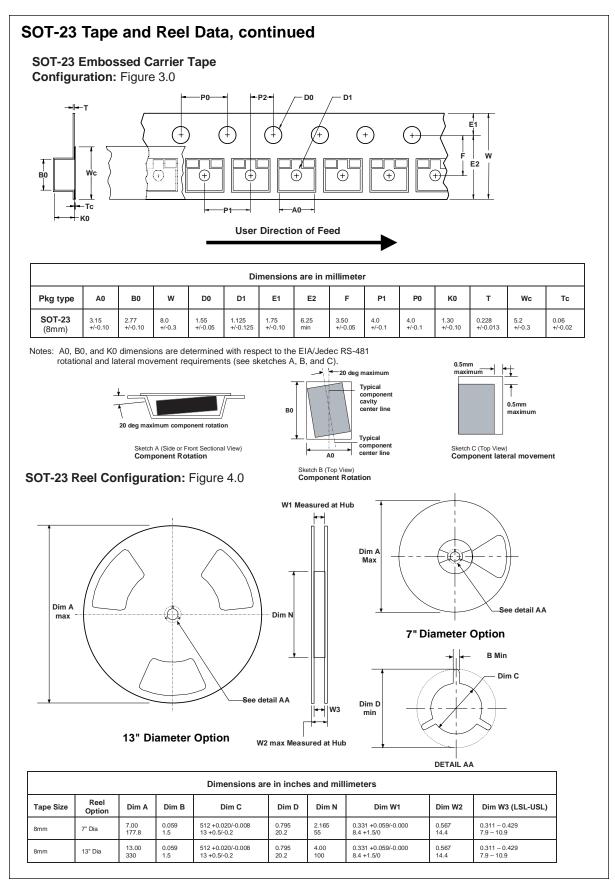
July 1999, Rev. A



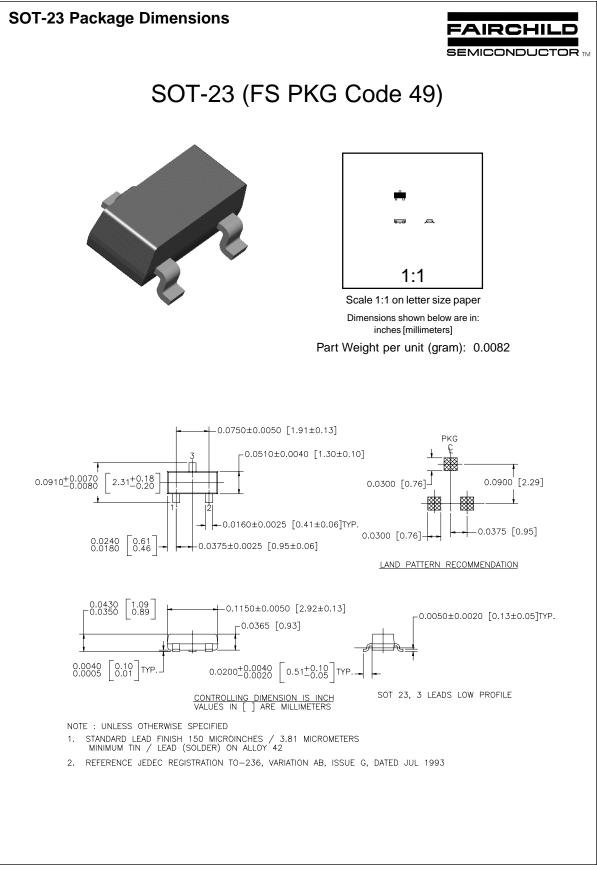


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Product status/pricing/packaging

Product	Product status	Pricing*	Package type	Leads	Package marking	Packing method
2N4124BU	Full Production	\$0.045	<u>TO-92</u>	3	N/A	BULK
2N4124TA	Full Production	\$0.045	<u>TO-92</u>	3	N/A	TAPE REEL
2N4124TF	Full Production	\$0.045	<u>TO-92</u>	3	N/A	TAPE REEL
2N4124RA	Full Production	\$0.073	TO-92	3	\$Y&3 2N 4124	TAPE REEL
2N4124	Full Production	\$0.073	TO-92	3	\$Y&3 2N 4124	BULK

\* 1,000 piece Budgetary Pricing

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Models

Package & leads Condition		Temperature range	Software version	Revision date
PSPICE				
TO-92-3	Electrical	25°C	N/A	N/A

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